DC/DC Step up Converter ME2108 Series
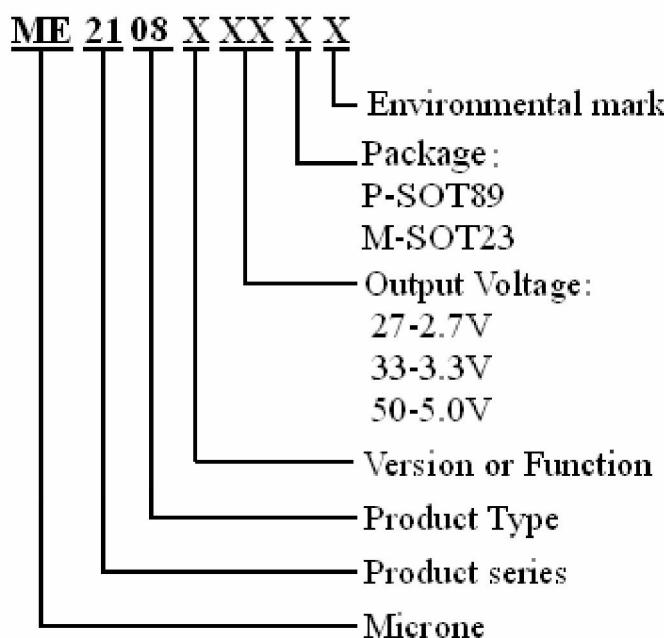
General Description

ME2108 Series is a PFM Step-up DC/DC converter IC with low supply current by CMOS process. High frequency noise that occurs during switching is reduced by using advanced circuit designed, output voltage is programmable in 0.1V steps between 2.0~7.0V and maximum frequency is 180KHz(Typ.). A low ripple, high efficiency step-up DC/DC converter can be constructed of ME2108Xxx with only three external components. Also available is a CE(chip enable) function that reduce power dissipation During shut-down mode. ME2108Xxx is suitable for use with battery-powered instruments with low noise and low supply current.

Features

l   Low ripple and low noise
l   Operating voltage range   0.9V~6.5V
l   Output voltage range   2.0V~7.0V(step 0.1V)
l   Output voltage accuracy   ±2.5%
l   Output Current   if Vin=3.0V and Vout=5.0V then Iout=400mA
l   Low start voltage   0.9V(at Iout=1mA)
l   Maximum oscillator frequency   180KHz(Typ.)
l   High Efficiency   85%(Type)
l   PACKAGE   SOT-23   SOT-23-3   SOT-89-3   SOT-89-5

Selection Guide

ME 2108 X XX X X
- Environmental mark
- Package：
  P-SOT89
  M-SOT23
- Output Voltage：
  27-2.7V
  33-3.3V
  50-5.0V
- Version or Function
- Product Type
- Product series
- Microne
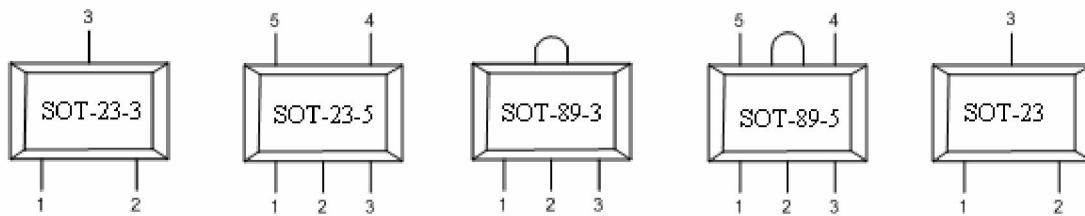
Applications

l   Power source for battery-powered equipment
l   Power source for wireless mouse, wireless keyboard, toys, cameras, camcorders, VCRs, PDAs, and hand-held communication equipment
l   Power source for appliances which require higher cell voltage than that of batteries used in the appliances

TYPE	POSTFIX	PACKAGE	SWITCHING TRANSISTOR	CE FUNCTION	FEATURES
ME2108Axx	M3	SOT-23-3	Build in Transistor	No	Lx
	P	SOT-89-3			
ME2108Bxx	M3	SOT-23-3	External Transistor	No	Ext
	P	SOT-89-3			
ME2108Cxx	M5	SOT-23-5	Build in Transistor	Yes	Lx CE
	P	SOT-89-5			
ME2108Dxx	M5	SOT-23-5	External Transistor	Yes	Ext CE
	P	SOT-89-5			
ME2108Dxx	M5	SOT-23-5	External Transistor	Yes	Ext

Pin Configuration

Pin Assignment

ME2108Axx

PIN Number		PIN NAME	FUNCTION
SOT-23-3/ SOT-23	SOT-89-3		
1	1	Vss	Ground
3	2	Vout	Output voltage monitor, IC internal power supply
2	3	Lx	Switch

ME2108Bxx

PIN Number		PIN NAME	FUNCTION
SOT-23-3/ SOT-23	SOT-89-3		
1	1	Vss	Ground
3	2	Vout	Output voltage monitor, IC internal power supply
2	3	Ext	External switch transistor drive

ME2108Cxx
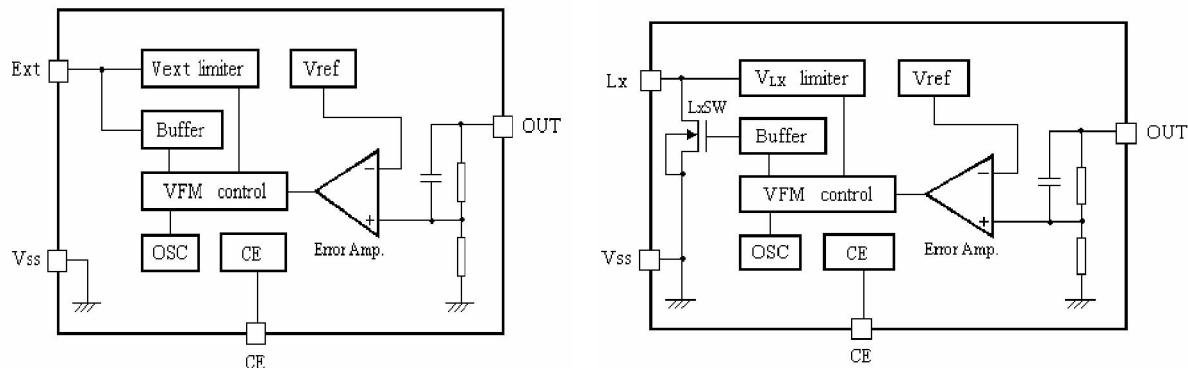
PIN Number		PIN NAME	FUNCTION
SOT-23-5	SOT-89-5		
4	5	Vss	Ground
2	2	Vout	Output voltage monitor, IC internal power supply
5	4	Lx	Switch
1	3	CE	Chip enable
3	1	NC	NC

ME2108Dxx

PIN Number		PIN NAME	FUNCTION
SOT-23-5	SOT-89-5		
4	5	Vss	Ground
2	2	Vout	Output voltage monitor, IC internal power supply
5	4	Ext	External switch transistor drive
1	3	CE	Chip enable
3	1	NC	NC

ME2108Fxx

PIN Number	PIN NAME	FUNCTION
SOT-23-5		
1	FB	Feed Back
2	Vdd	Output voltage monitor, IC internal power supply
3	NC	NC
4	Vss	Ground
5	EXT	External switch transistor drive

Block Diagram

Absolute Maximum Ratings

PARAMETER		SYMBAL	RATINGS	UNITS
V_{IN} Input Voltage		V_{IN}	6.5	V
Lx Pin voltage		V_{LX}	6.5	V
EXT Pin voltage		V_{EXT}	-0.3~Vout+0.3	V
CE Pin voltage		V_{CE}	-0.3~Vout+0.3	V
Lx Pin current		I_{LX}	600	mA
EXT Pin current		I_{EXT}	±30	mA
Vdd input voltage		V_{dd}	6.5	V
Continuous Total Power Dissipation	SOT-23	Pd	300	mW
	SOT-89	Pd	500	mW
Operating Ambient Temperature		T_{Opr}	-25~+85	
Storage Temperature		T_{stg}	-40~+125	
Soldering temperature and time		T_{solder}	260 , 10s	

Electrical Characteristics

Measuring conditions   Unless otherwise specified , V_{IN}=Vout*0.6 V_{SS}=0V I_{OUT}=10mA T_{opt}=25

ME2108Axx/Cxx   Fosc=180kHz

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
V_{OUT}	Output Voltage		Vout*0.975	Vout	Vout*1.025	V
V_{start}	Oscillation Start-up Voltage	I_{OUT}=1mA V_{IN} 0 2V		0.8	0.9	V
V_{hold}	Oscillation Hold Voltage	I_{OUT}=1mA V_{IN} 2 0V		0.45		V
I_{DD1}	Supply Current 1	No external component Vout=Vout*0.95,		50		μA
I_{DD2}	Supply Current 2	Vout=Vout+0.5V		9		μA
I_{LX}	Lx Switching Current	V_{LX}=0.4V, Vout=Vout*0.95		360		mA
I_{LXleak}	Lx Leakage Current	Vout=V_{LX}=6V			0.5	μA
F_{osc}	Oscillation Frequency	Vout=set Vout*0.95		180		kHz
Maxdty	Duty Ratio	on(V_{LX}"L")side		84		%
EFFI	Efficiency			85		%

ME2108Bxx/Dxx   Fosc=180kHz

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
V_{OUT}	Output Voltage		Vout*0.975	Vout	Vout*1.025	V
V_{start}	Oscillation Start-up Voltage	I_{OUT}=1mA V_{IN} 0 2V		0.8	0.9	V
V_{hold}	Oscillation Hold Voltage	I_{OUT}=1mA V_{IN} 2 0V		0.45		V
I_{DD1}	Supply Current 1	No external component Vout=Vout*0.95,		80		μA
I_{DD2}	Supply Current 2	Vout=Vout+0.5V		12		μA
I_{LX}	Lx Switching Current	V_{LX}=0.4V, Vout=Vout*0.95		360		mA
I_{LXleak}	Lx Leakage Current	Vout=V_{LX}=6V			0.5	μA
F_{osc}	Oscillation Frequency	Vout=set Vout*0.95		180		kHz
Maxdty	Duty Ratio	on(V_{LX}"L")side		84		%
EFFI	Efficiency			85		%

ME2108F   VFB=3.3V , Fosc=180kHz

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
V_{FB}	Output Feedback Voltage		3.22	3.3	3.38	V
V_{start}	Oscillation Start-up Voltage	I_{OUT}=1mA V_{IN} 0 2V		0.8	0.9	V
V_{hold}	Oscillation Hold Voltage	I_{OUT}=1mA V_{IN} 2 0V		0.45		V
I_{DD1}	Supply Current 1	No external component Vout=Vout*0.95,		80		μA
I_{DD2}	Supply Current 2	Vout=Vout+0.5V		10		μA
I_{LX}	Lx Switching Current	V_{LX}=0.4V, Vout=Vout*0.95		360		mA
I_{LXleak}	Lx Leakage Current	Vout=V_{LX}=6V			0.5	μA
F_{osc}	Oscillation Frequency	Vout=set Vout*0.95		180		kHz
Maxdty	Duty Ratio	on(V_{LX}"L")side		84		%
EFFI	Efficiency			85		%
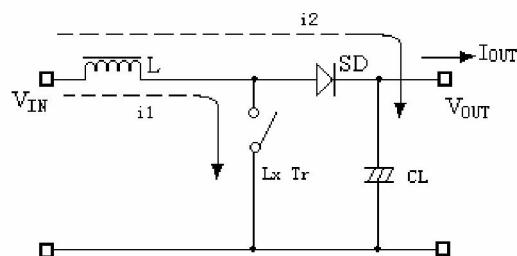
Note   1   Diode use Schottky diode such as IN5817 or   IN5819 (forward voltage drop:0.2V)

   2   Inductor   33μH   r<0.5

   3   Capacitor   Tantalum type 100μF

Operation

ME2108 step-up DC/DC converter charges energy in the inductor when Lx Transistor is on, and discharges the energy with the addition of the energy from input power source thereto, so that a higher output voltage than the input voltage is obtained. Following is the operation diagram.

Switching DC/DC Step up Converter operating process

Selection of Peripheral Components and Application Notes
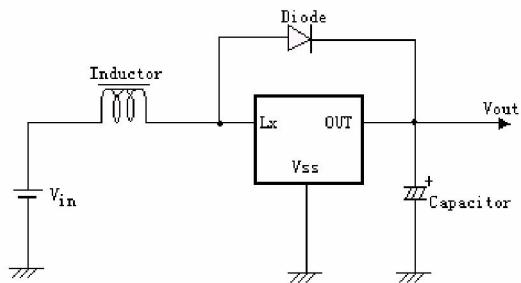
Peripheral components should be selected carefully because they are greatly affect the performances of ME2108

Ø   Use capacitor with a capacity of 10μF or more (too small capacity will lead to high output ripple), and with good frequency characteristics (it is better to use Tantalum type). Besides, it is recommended the use of a capacitor with an allowable voltage which is at least three times the output set voltage. This is because there may be the case where a spike-shaped high voltage is generated by the inductor when Lx transistor is turned OFF.

Ø   Choose such an inductor that has sufficiently small d.c. resistance and large allowable current, and hardly reaches magnetic saturation. When the inductance value of the inductor is small, there may be the case where I_{LX} exceeds the absolute maximum ratings at the maximum load.

Ø   Use a diode of a Schottky type with high switching speed.
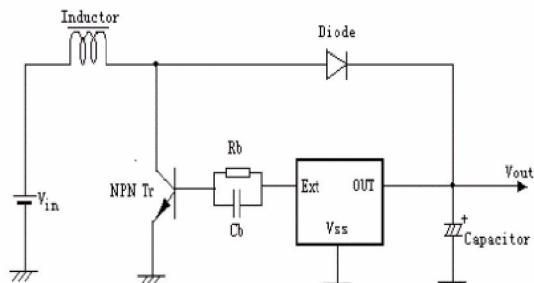
PCBLAYOUT

Ø   Set external components as close as possible to the IC and minimize the connection between the components and the IC. In particular, when an external component is connected to V_{OUT} Pin, make minimum connection with the capacitor.

Ø   Make Vss pin sufficient grounding, otherwise, the zero level within IC will varied with the switching current. This may result in unstable operation of IC.
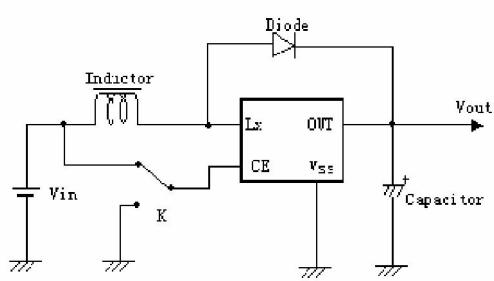
Typical Applications
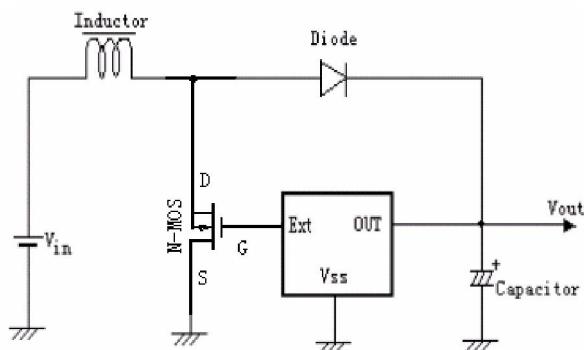
For use Build_in Transistor
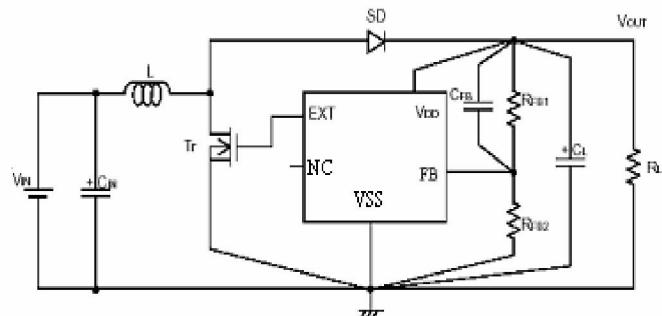
For use External Transistor

For use Chip Enable(CE)

For use external transistor(N_MOS)

For use FB & extermal

Components   Inductor   47uH(Sumida)   Diode   IN5817   IN5819
Capacitor   47uF/16V(Tantalum type)   Transistor   2SD1628G   2SD3279
NMOS   AAT9460   XP151   XP161   Base Resistor(Rb)   1K
Base Capacitor(Cb)   2200pF
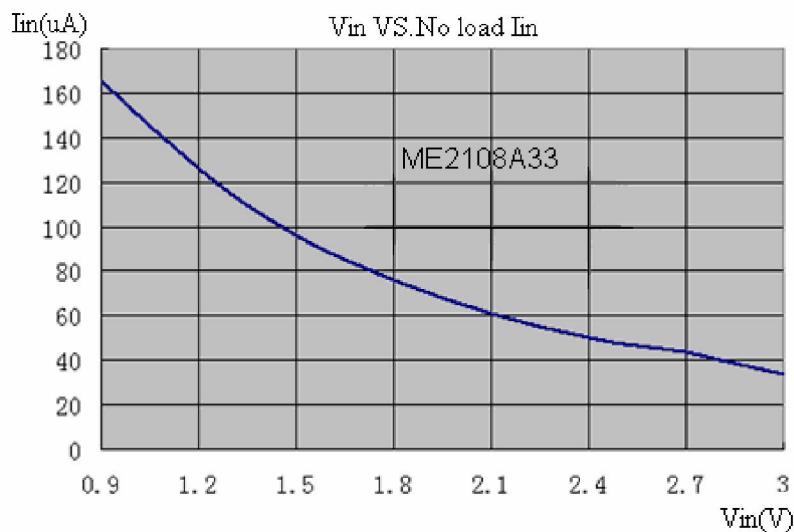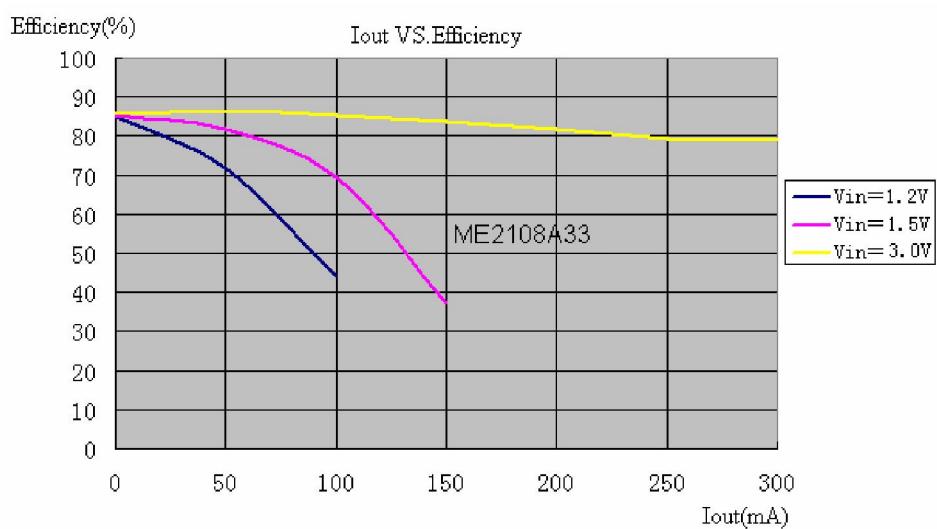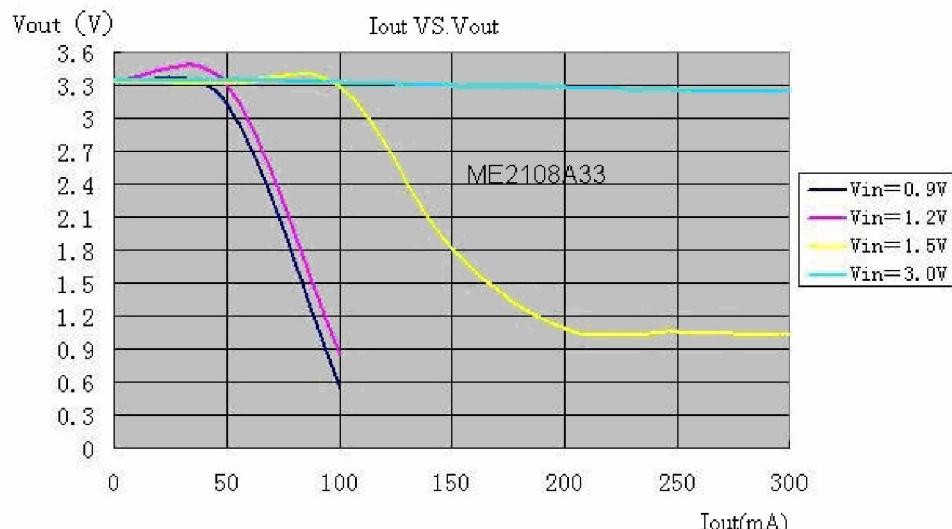
R_{FB} :Set up so that R_{FB1} /R_{FB2}=Vout / V_{FB}-1(Vout=set-up output voltage),
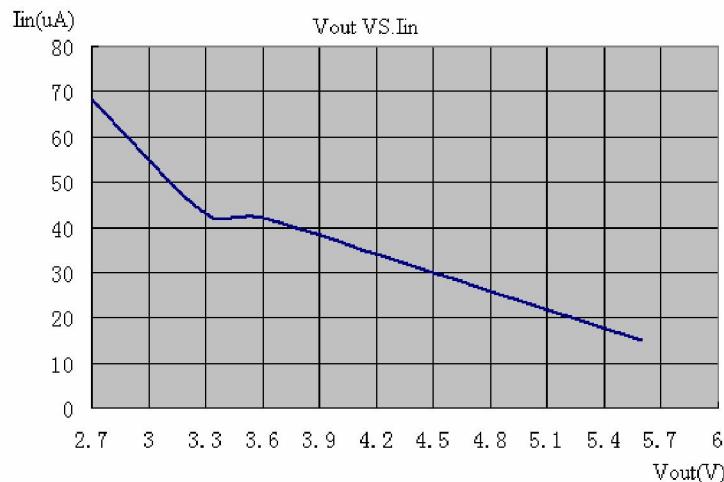
Please use with R_{FB1}+R_{FB2} 2M   ;

C_{FB}:Set up that Fzfb=$1/(2\times \times C_{FB} \times R_{FB1})$ is within the Adjustments necessary in respect of L,C_L.
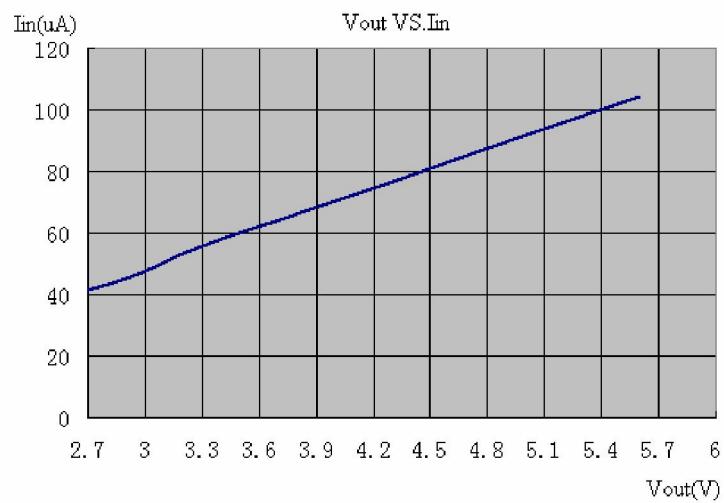
Type Characteristics
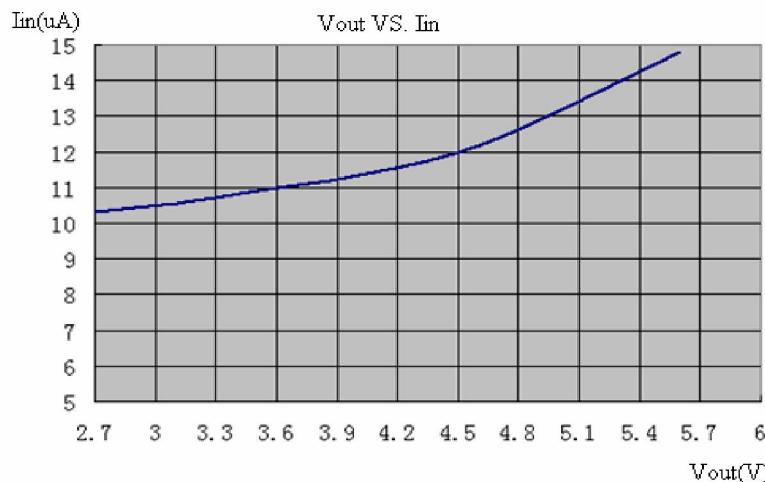
L   47uH   Cout   47uF   Vout=100uF   SD   1N5717/5819

$V_{DD}=V_{OUT}*0.95$

$V_{DD}=V_{OUT}$ 0.5

OSC(KHz)   Vout VS. OSC

Duty Ratio(%)   Vout VS. Duty Ratio
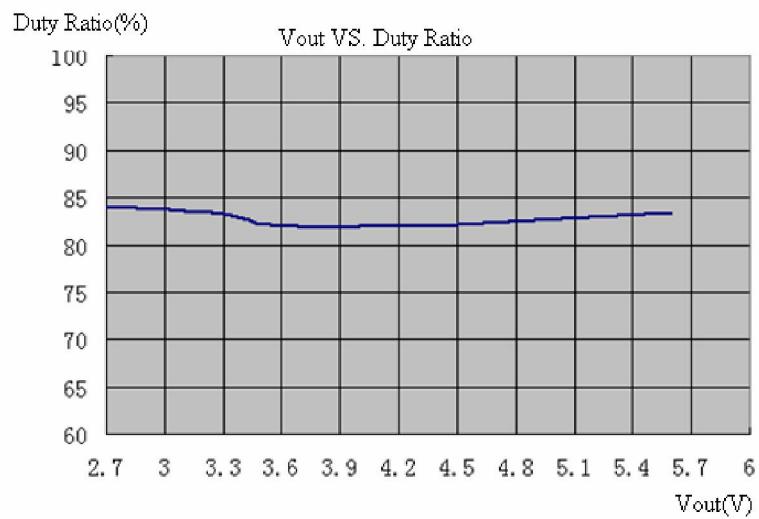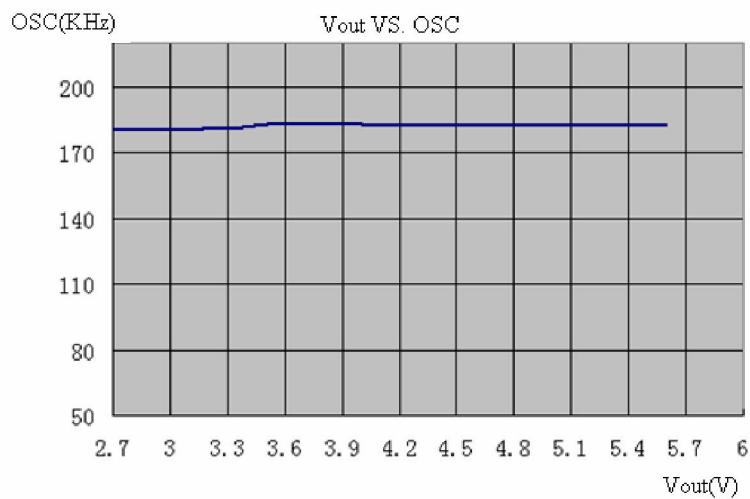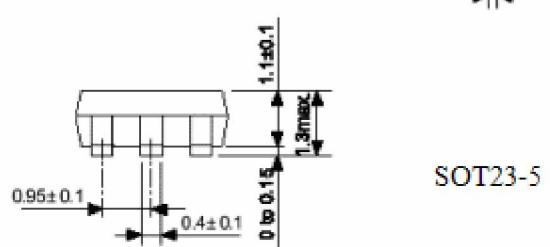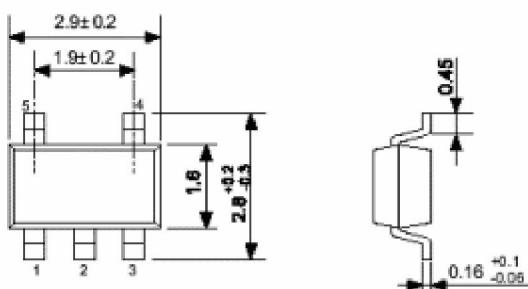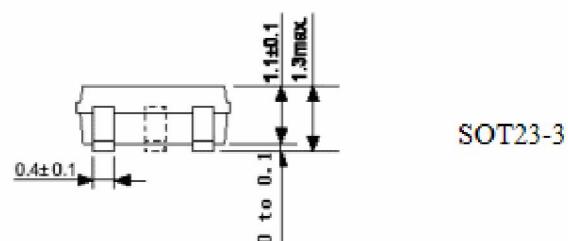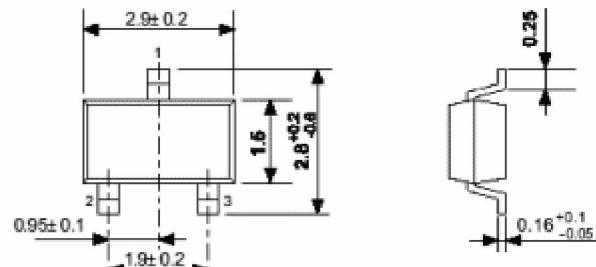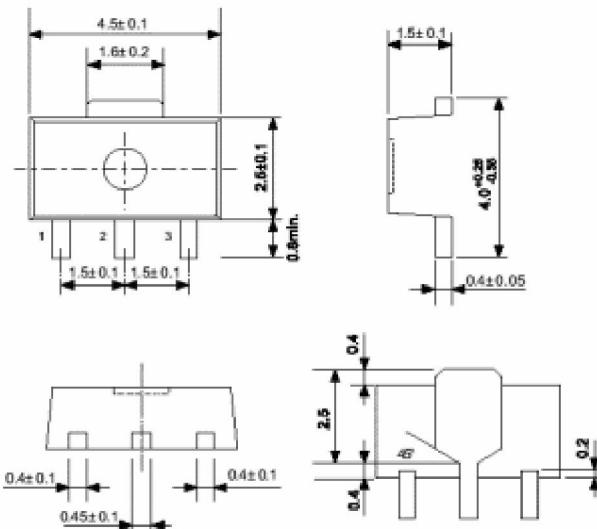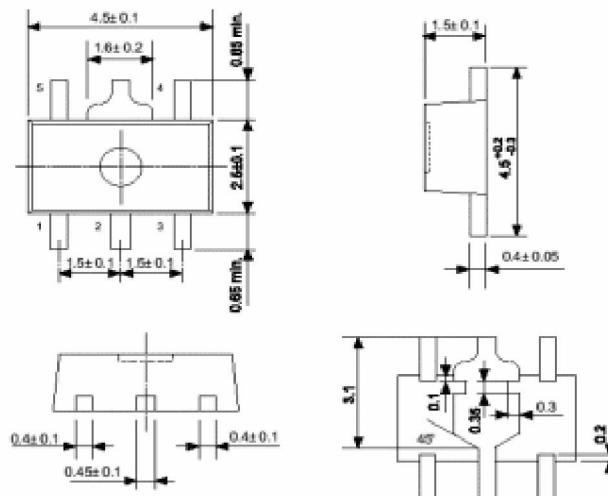
## Package Dimensions

SOT23-3

SOT23-5

SOT89-3

SOT89-5

SOT23
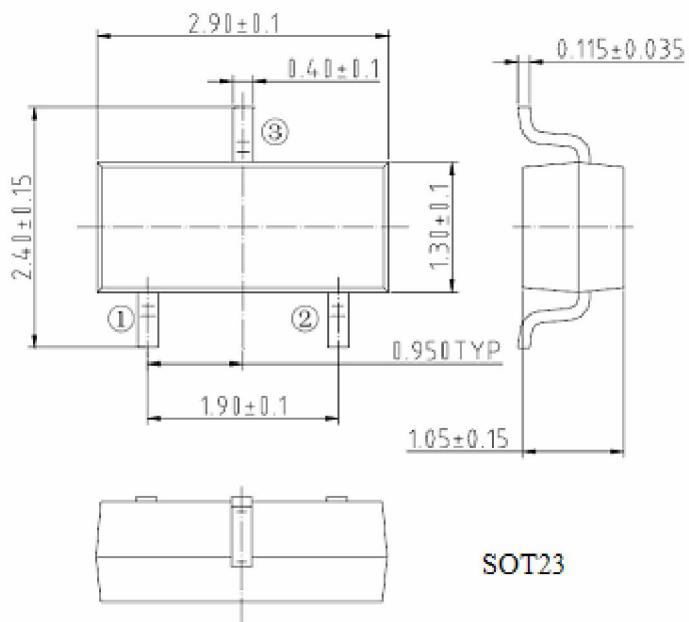
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